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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/940,792	08/29/2001	Paul A. Farrar	M4065.0382/P382-A	5268
24998	7590	06/13/2005	EXAMINER	
DICKSTEIN SHAPIRO MORIN & OSHINSKY LLP			LEE, EUGENE	
2101 L Street, NW			ART UNIT	
Washington, DC 20037			PAPER NUMBER	
			2815	

DATE MAILED: 06/13/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary

Application No.

09/940,792

Applicant(s)

FARRAR ET AL.

Examiner

Eugene Lee

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-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --
Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☒ Responsive to communication(s) filed on 09 May 2005.
2a) ☐ This action is FINAL. 2b) ☒ This action is non-final.
3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 46-48, 51-56, 58-60, 62-65 and 67-81 is/are pending in the application.
4a) Of the above claim(s) _____ is/are withdrawn from consideration.
5) ☐ Claim(s) _____ is/are allowed.
6) ☒ Claim(s) 46-48, 51-56, 58-60, 62-65 and 67-81 is/are rejected.
7) ☐ Claim(s) _____ is/are objected to.
8) ☐ Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
10) ☐ The drawing(s) filed on _____ is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
a) ☐ All b) ☐ Some * c) ☐ None of:
1. ☐ Certified copies of the priority documents have been received.
2. ☐ Certified copies of the priority documents have been received in Application No. _____.
3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

- 1) ☒ Notice of References Cited (PTO-892)
2) ☐ Notice of Draftsperson's Patent Drawing Review (PTO-948)
3) ☐ Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)
Paper No(s)/Mail Date _____.
4) ☐ Interview Summary (PTO-413)
Paper No(s)/Mail Date _____.
5) ☐ Notice of Informal Patent Application (PTO-152)
6) ☐ Other: _____.

DETAILED ACTION

Continued Examination Under 37 CFR 1.114

1. A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on 5/9/05 has been entered.

Claim Rejections - 35 USC § 112

2. The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

3. Claims 56, 58 thru 60, 62 thru 65, and 67 thru 71 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

Claim 56 recites the limitation "buried conductor pattern" in line 11 of said claim. There is insufficient antecedent basis for this limitation in the claim.

It is not clear whether the limitation "buried conductor pattern" refers to the "buried conductor pattern" in the preamble or the "empty-shaped pattern" in line 3 of said claim. It appears from the claims that it should refer back to the "empty-shaped pattern." However, appropriate clarification and/or correction is required.

Claim 62 recites the limitation "conductive structure" in line 11 of said claim. There is insufficient antecedent basis for this limitation in the claim.

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It is not clear whether the limitation “conductive structure” refers to the “conductive structure” in line 5 of said claim or the “empty space pattern” in line 6 of said claim. It appears from the claims that it should refer back to the “empty space pattern.” However, appropriate clarification and/or correction is required.

Claim Rejections - 35 USC § 103

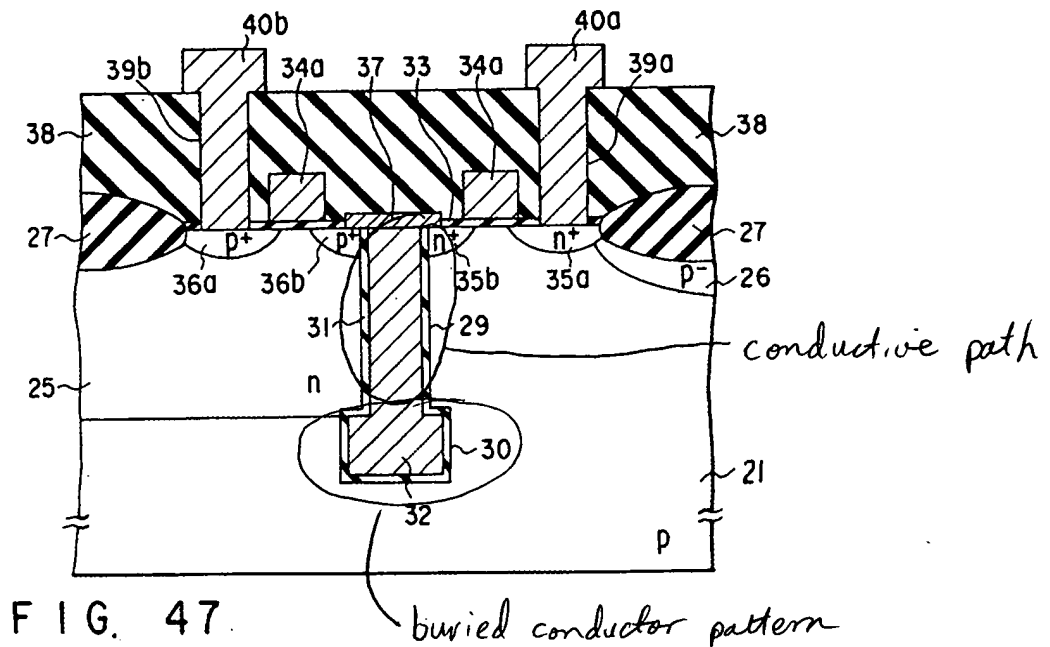
4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

5. Claims 46, 51, 52, 55, 56, 58, 59, 72, and 75 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yamamoto et al. 5,963,838 in view of Bai et al. 5,861,340.

Yamamoto discloses (see, for example, FIG. 47) an integrated circuit substrate comprising a substrate 21, and bottom rectangular-shaped wiring layer (buried conductor pattern) 32. The bottom rectangular-shaped wiring layer is completely surrounded by the substrate, and forms an interconnect between MOS transistor (devices) 34a. A conductive path from the bottom rectangular-shaped wiring layer extends to said MOS transistors. A portion of the conductive path extends below a top surface of said substrate.

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Yamamoto does not disclose a monocrystalline substrate. However, Bai discloses (see, for example, column 3, lines 34-36) a monocrystalline substrate. It would have been obvious to one of ordinary skill in the art at the time of invention to have a monocrystalline substrate in order to have a substrate with less crystal defects.

Regarding claim 51, see column 22, lines 13-15 wherein Yamamoto discloses the wiring layer being made of tungsten.

Regarding claim 52, see column 19, lines 30-35 wherein Yamamoto discloses a silicon substrate.

Regarding claim 56, Yamamoto discloses (see, for example, FIG. 47) an integrated circuit substrate comprising a substrate 21, and bottom rectangular-shaped wiring layer (at least one empty-spaced pattern) 32. The bottom rectangular-shaped wiring layer is completely surrounded by the substrate, and connects forms an interconnect between MOS transistor (devices) 34a. A conductive path from the bottom

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rectangular-shaped wiring layer connects the empty-shaped pattern with the exterior of said substrate. A portion of the conductive path extends below a top surface of said substrate. Yamamoto does not disclose a monocrystalline substrate. However, Bai discloses (see, for example, column 3, lines 34-36) a monocrystalline substrate. It would have been obvious to one of ordinary skill in the art at the time of invention to have a monocrystalline substrate in order to have a substrate with less crystal defects.

Regarding claim 58, see, for example, FIG. 47 wherein Yamamoto clearly discloses the bottom rectangular shaped wiring layer 32 having a pipe-shaped/plate-shaped configuration.

6. Claims 47, 48, 73, 76 thru 79, and 81 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yamamoto et al. '838 in view of Bai et al. 5,861,340 as applied to claims 46, 51, 52, 55, 56, 58, 59, 72, and 75 above, and further in view of Kenney 5,583,368. Yamamoto in view of Bai does not disclose a second buried conductor pattern having a pipe-shaped or plate-shaped pattern, and said first buried conductor pattern being located below said second buried conductor pattern. However, Kenney discloses (see, for example, FIG. 1g) subsurface structures (for contacts to and connectors between devices) comprising trenches of varying depths. It would have been obvious to one of ordinary skill in the art at the time of invention to have a second buried conductor pattern having a pipe-shaped or plate-shaped pattern, and said first buried conductor pattern being located below said second buried conductor pattern in order to form multiple contacts within a semiconductor device and form greater circuit integration.

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In addition, the use of a plate-shaped or pipe-shaped pattern or any other combination of patterns within the same device does not provide any critical or unexpected results to the applicant's invention. Rather, it is merely an obvious design choice determinable by routine experimentation. In *Aller*, the court stated, "Where the general conditions of a claim are disclosed in the prior art, it is not inventive to discover the optimum or workable ranges by routine experimentation." In *re Aller*, 220 F.2d 454, 456 105 USPQ 233,235 (CCPA 1995).

7. Claim 53 is rejected under 35 U.S.C. 103(a) as being unpatentable over Yamamoto et al. '838 in view of Bai et al. '340 as applied to claims 46, 51, 52, 55, 56, 58, 59, 72, and 75 above, and further in view of Witek et al. 5,291,438. Yamamoto in view of Bai does not disclose said monocrystalline substrate being a germanium substrate. However, germanium is one of many conventional materials used in the fabrication of semiconductor devices. In column 3, lines 63-65, Witek discloses germanium as a substrate material. Therefore it would have been obvious to one of ordinary skill in the art at the time of invention to use a germanium substrate in order to support a semiconductor device on a substrate because it has been held to be within the general skill of a worker in the art to select a known material on the basis of its suitability for the intended use as a matter of obvious design choice. In *re Leshin*, 125 USPQ 416.

8. Claim 54 is rejected under 35 U.S.C. 103(a) as being unpatentable over Yamamoto et al. '838 in view of Bai et al. 5,861,340 as applied to claims 46, 51, 52, 55, 56, 58, 59, 72, and 75 above, and further in view of Noguchi 6,437,403 B1. Yamamoto

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in view of Bai does not disclose a silicon-on-insulator substrate. However, Noguchi discloses (see, for example, column 1, lines 16-34) that Silicon on Insulator reduces parasitic capacity of transistors. It would have been obvious to one of ordinary skill in the art at the time of invention to have a silicon-on-insulator substrate in order to reduce parasitic capacity of transistors.

9. Claim 60 is rejected under 35 U.S.C. 103(a) as being unpatentable over Yamamoto et al. '838 in view of Bai et al. 5,861,340 as applied to claims 46, 51, 52, 55, 56, 58, 59, 72, and 75 above, and further in view of Sato et al. "A New Substrate Engineering for the Formation of Empty Space in Silicon Induced by Silicon Surface Migration." Yamamoto in view of Bai does not disclose a sphere-shaped configuration. However, Sato discloses (see, for example, column 2, lines 4-7) a spherical pattern as one of many patterns that are formed within a substrate. Therefore it would have been obvious to one of ordinary skill in the art at the time of invention to have a sphere-shaped configuration or a spherical pattern in order to form a buried pattern that supports semiconductor devices under the surface of a substrate.

Also, the use of a spherical pattern does not provide any critical or unexpected results to the applicant's invention. Rather, it is merely an obvious design choice determinable by routine experimentation. In *Aller*, the court stated, "Where the general conditions of a claim are disclosed in the prior art, it is not inventive to discover the optimum or workable ranges by routine experimentation." In *re Aller*, 220 F.2d 454, 456 105 USPQ 233,235 (CCPA 1995).

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10. Claims 62 thru 64, and 67 thru 71 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yamamoto et al. '838 in view of Bai et al. 5,861,340 as applied to claims 46, 51, 52, 55, 56, 58, 59, 72, and 75 above, and further in view of Tsu et al. 6,294,420 B1. Yamamoto in view of Bai does not disclose a processor system and a circuit coupled to said processor. However, Tsu discloses (see, for example, FIG. 4C and FIG. 6) a memory array comprising a processor coupled to additional circuitry. In column 8, lines 61- column 9, line 7, Tsu states that the memory array may be embedded into a larger integrated circuit device wherein the memory array is included with control circuitry on the same integrated circuit. Therefore, it would have been obvious to one of ordinary skill in the art at the time of invention to have a processor system and a circuit coupled to said processor in order to utilize the device in memory circuits.

Regarding the limitation "said conductive structure" in line 11 of said claim, see, for example, FIG. 47 wherein Yamamoto clearly discloses the bottom rectangular shaped wiring layer (conductive structure) 32.

Regarding claims 63, and 64, see, for example, FIG. 47 wherein Yamamoto clearly discloses the bottom rectangular shaped wiring layer 32 having a pipe-shaped/plate-shaped configuration.

11. Claim 65 is rejected under 35 U.S.C. 103(a) as being unpatentable over Yamamoto et al. '838 in view of Bai et al. 5,861,340 in view of Tsu et al. '420 B1 as applied to claims 62-64, and 67-71 above, and further in view of Sato et al. "A New Substrate Engineering for the Formation of Empty Space in Silicon Induced by Silicon Surface Migration." Yamamoto in view of Bai in view of Tsu does not disclose a sphere-

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shaped configuration. However, Sato discloses (see, for example, column 2, lines 4-7) a spherical pattern as one of many patterns that are formed within a substrate. Therefore it would have been obvious to one of ordinary skill in the art at the time of invention to have a sphere-shaped configuration or a spherical pattern in order to form a buried pattern that supports semiconductor devices under the surface of a substrate.

Also, the use of a spherical pattern does not provide any critical or unexpected results to the applicant's invention. Rather, it is merely an obvious design choice determinable by routine experimentation. In *Aller*, the court stated, "Where the general conditions of a claim are disclosed in the prior art, it is not inventive to discover the optimum or workable ranges by routine experimentation." In *re Aller*, 220 F.2d 454, 456 105 USPQ 233,235 (CCPA 1995).

12. Claims 74, and 80 is rejected under 35 U.S.C. 103(a) as being unpatentable over Yamamoto et al. '838 in view of Bai et al. 5,861,340 in view of Kenney '368 as applied to claims 47, 48, 73, 76-79, and 81 above, and further in view of Sato et al. "A New Substrate Engineering for the Formation of Empty Space in Silicon Induced by Silicon Surface Migration." Yamamoto in view of Bai in view of Kenney does not disclose a sphere-shaped configuration or a spherical pattern. However, Sato discloses (see, for example, column 2, lines 4-7) a spherical pattern as one of many patterns that are formed within a substrate. Therefore it would have been obvious to one of ordinary skill in the art at the time of invention to have a sphere-shaped configuration or a spherical pattern in order to form a buried pattern that supports semiconductor devices under the surface of a substrate.

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Also, the use of a spherical pattern does not provide any critical or unexpected results to the applicant's invention. Rather, it is merely an obvious design choice determinable by routine experimentation. In *Aller*, the court stated, "Where the general conditions of a claim are disclosed in the prior art, it is not inventive to discover the optimum or workable ranges by routine experimentation." In *re Aller*, 220 F.2d 454, 456 105 USPQ 233,235 (CCPA

Response to Arguments

13. Applicant's arguments with respect to claims 46-48, 51-56, 58-60, 62-65, and 67-81 have been considered but are moot in view of the new ground(s) of rejection.

INFORMATION ON HOW TO CONTACT THE USPTO

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Eugene Lee whose telephone number is 571-272-1733. The examiner can normally be reached on M-F 8-5.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Tom Thomas can be reached on 571-272-1664. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Eugene Lee
June 8, 2005

A handwritten signature in black ink, appearing to read 'Eugene Lee', located below the typed name and date.A large handwritten checkmark in black ink, located to the right of the typed name and date.